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PATENT & TRADEMARK OFFICE

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Pierre C. Fazan et al.

Title: METHOD FOR FORMING A STORAGE CELL CAPACITOR COMPATIBLE WITH HIGH DIELECTRIC CONSTANT MATERIALS

Docket No.: 303.434US2

Serial No.: 09/489,954

Filed: January 24, 2000

Due Date: February 6, 2003

Examiner: Donghee Kang

Group Art Unit: 2811

Box AF

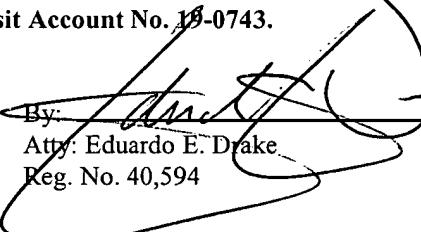
Commissioner for Patents
Washington, D.C. 20231

We are transmitting herewith the following attached items (as indicated with an "X"):

A return postcard.
 An Amendment and Response (5 Pages).
 A Clean Version of Pending Claims (8 pgs.).

Please consider this a PETITION FOR EXTENSION OF TIME for sufficient number of months to enter these papers and please charge any additional required fees or credit overpayment to Deposit Account No. 10-0743.

SCHWEGMAN, LUNDBERG, WOESSNER & KLUTH, P.A.
P.O. Box 2938, Minneapolis, MN 55402 (612-373-6900)

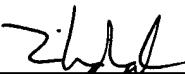
By: 
Atty: Eduardo E. Drake
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CERTIFICATE UNDER 37 CFR 1.8: The undersigned hereby certifies that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail, in an envelope addressed to: Box AF, Commissioner for Patents, Washington, D.C. 20231, on this 6 day of January, 2003.

Name

Tina Kohlout

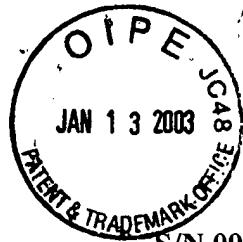
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EXPEDITED PROCEDURE - EXAMINING GROUP 2811

S/N 09/489,954

PATENT

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(RE)
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L. Spruill
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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Pierre C. Fazan et al. Examiner: Donghee Kang
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AMENDMENT & RESPONSE UNDER 37 C.F.R. § 1.116

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In response to the final Office Action mailed November 6, 2002, please amend the application as follows:

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IN THE CLAIMS

Please substitute the claim set in the appendix entitled Clean Version of Pending Claims for the previously pending claim set. The substitute claim set is intended to reflect amendment of previously pending claims 51-53, 105-107, and 113. The specific amendments to the individual claims are detailed in the following marked up set of claims.

51. (Amended) A dynamic random access memory device comprising:
a capacitor includingan electrode which comprises:
a) a first portion formed in an insulative layer having an upper surface;
b) a second portion overlying the first portion, wherein said insulative layer surrounds a sidewall of said second portion and said second portion does not extend above said upper surface; and
c) a third portion overlying said second portion and, extending above and below said upper surface of said insulative layer, and including a recess, wherein said first portion and said second portion are different materials.